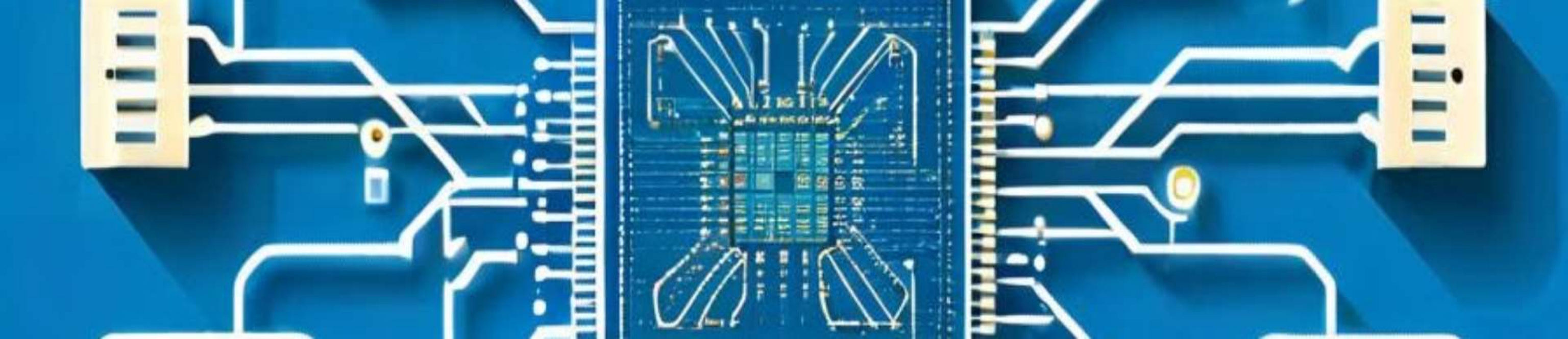


# MEMRISTOR BASED CONTENT ADDRESSABLE MEMORY

Presented By-

Pial Sarker Turjo,2021CSB018

Pantho Propan Debnath,2021CSB041



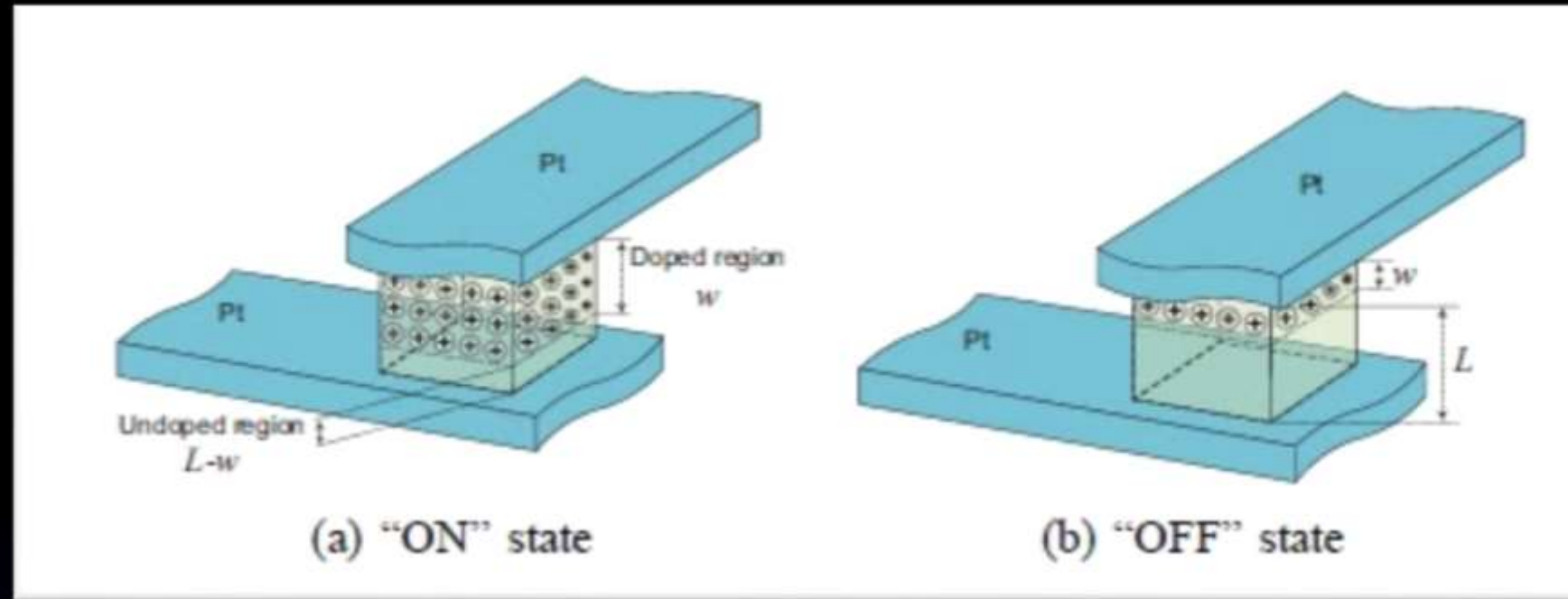
## **Memristor-based Content Addressable Memory**

Memristor-based Content Addressable Memory (MCAM) is an emerging memory technology that combines the advantages of content-addressable memory and memristor devices. This innovative approach promises significantly improved energy efficiency, faster access times, and increased storage density compared to traditional memory architectures.

# Principles of Memristor Operation:

Memristors, or memory resistors, are a unique type of electronic component that can "remember" their previous state even when power is removed. This memory property is achieved through the dynamic resistance change of the device based on the history of applied voltages and currents.

The fundamental principle behind memristor operation is the **drift and diffusion of ions** within the device's semiconductor material. By controlling the movement of these ions, the resistance can be precisely tuned, enabling non-volatile memory storage and advanced computing applications.



# Memristor Device Characteristics

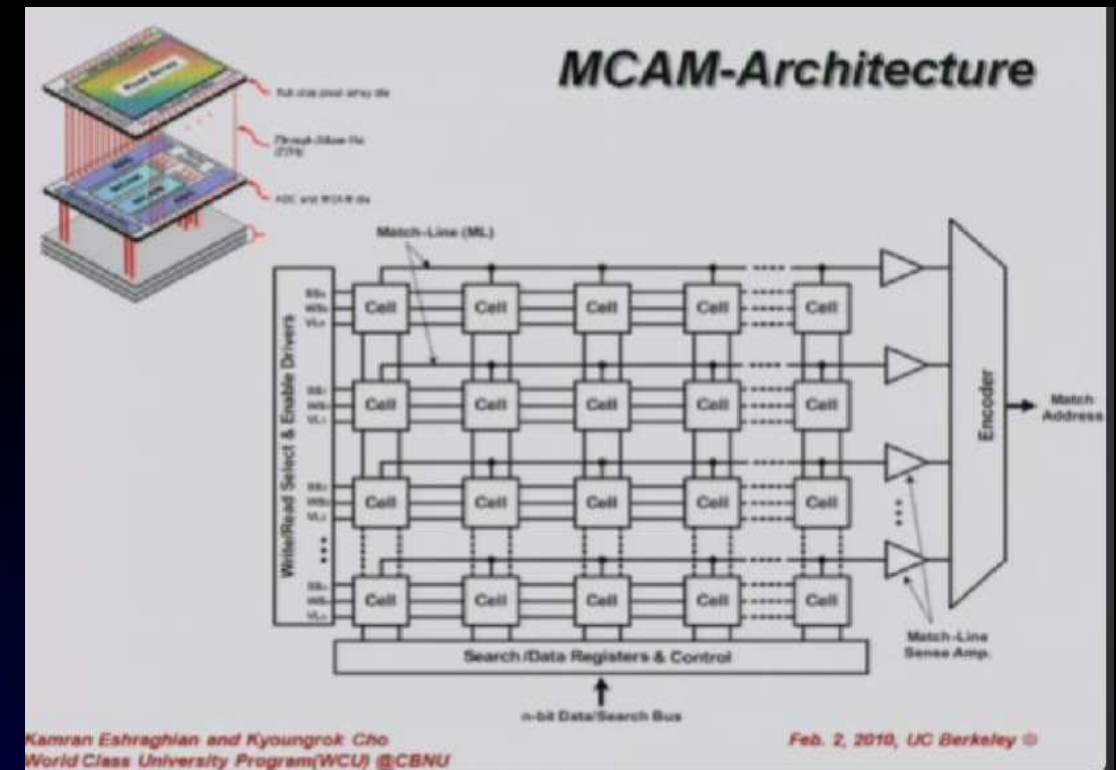
Memristors are two-terminal nanoscale resistive devices that exhibit unique nonlinear current-voltage characteristics and the ability to retain their resistance state even in the absence of power. This memristive behavior arises from the migration and redistribution of ions within the device's metal-insulator-metal structure.

Key characteristics of memristors include their high scalability, fast switching speed, low power consumption, and excellent endurance - enabling their use in dense, low-power, and high-performance memory and logic applications.

# ***What is CAM?***

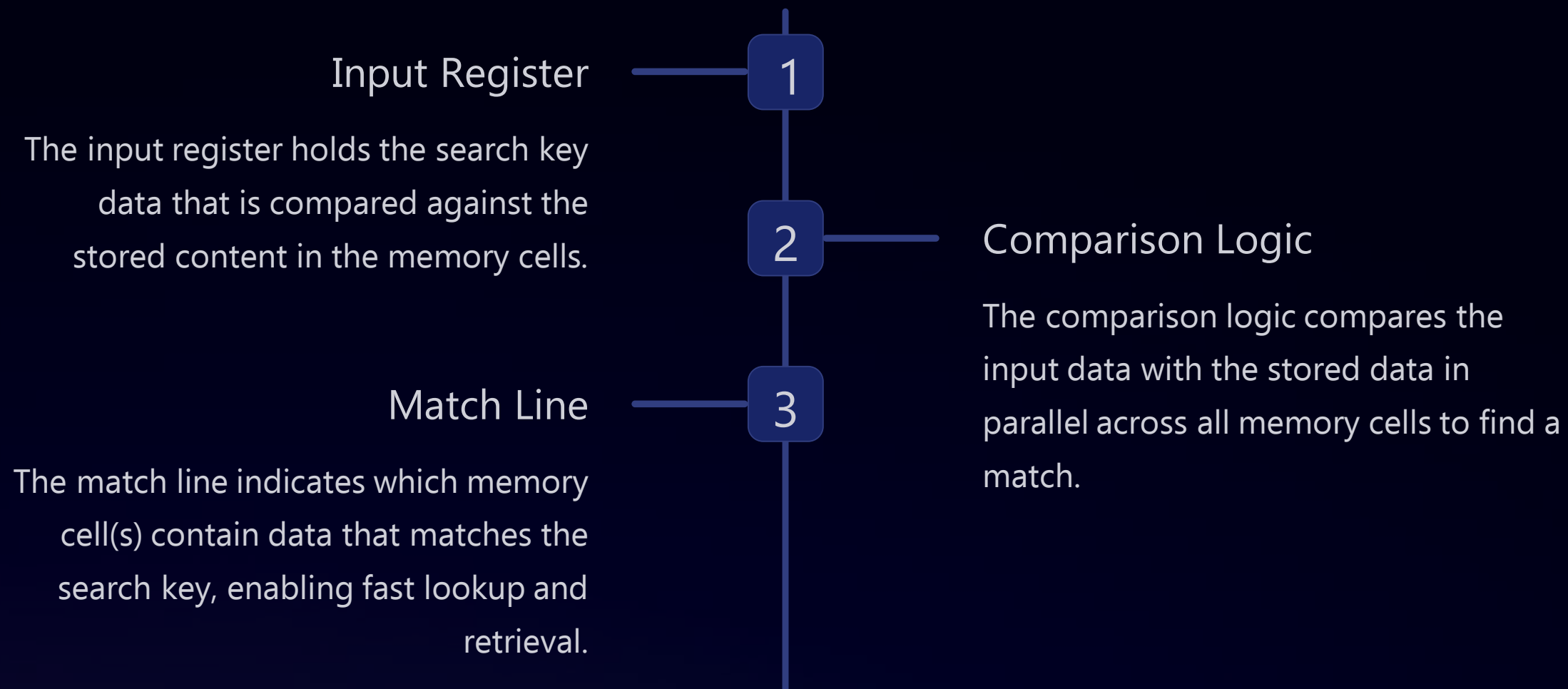
Content-addressable memory (CAM) is a special type of computer memory used in certain very-high-speed searching applications. It is also known as associative memory or associative storage and compares input search data against a table of stored data, and returns the address of matching data.

CAM is frequently used in networking devices where it speeds up forwarding information base and routing table operations. This kind of associative memory is also used in cache memory. In associative cache memory, both address and content is stored side by side. When the address matches, the corresponding content is fetched from cache memory.





# Content Addressable Memory Architecture



# Traditional CAM vs. Memristor-based CAM

## Traditional CAM

Conventional CAM uses static random-access memory (SRAM) cells, which are fast but consume more power and have limited scalability.

## Memristor-based CAM

Memristor-based CAM, on the other hand, leverages memristors as storage elements, offering lower power consumption, higher density, and potential for non-volatile operation.

### Conventional CAM Cell

#### 10-T NOR-type CAM cell

#### 8-T Subthreshold SRAM Cell [2]

**Need this complex structure for SRAM as transistors shrink**

**Problems:**

- Area utilization
- Power consumption
- CMOS needs wells and plugs

[2] N. Verno and A.P. Chandrakasan, A 256 kb/s 55 nm 8T Subthreshold SRAM Employing Sense-Amplifier Redundancy, IEEE J. Solid-St. Circ., 45(1):141-148, Jan. 2008.

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### Memristor-based CAM (MCAM) CELL:

- No wells – packed logic
- Area reduction – 46%
- Power reduction
- Fast Read - 10ns
- Slow Write – for now

	Cell Area	Average Power
CMOS CAM	40 $\mu\text{m}^2$	15.65 $\mu\text{W}$
MCAM	20 $\mu\text{m}^2$	0.12 $\mu\text{W}$

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# Advantages of Memristor-based CAM

- **Energy Efficiency:** Memristor-based CAM devices consume significantly less power compared to traditional CMOS-based CAM designs due to their non-volatile and low-power operation.
- **Scalability:** The nanoscale size of memristor devices enables high-density CAM arrays, allowing for more compact and scalable designs.
- **Fast Parallel Search:** The inherent parallelism of memristor-based CAM enables rapid, concurrent search operations, leading to faster data retrieval and processing.



# Applications of Memristor-based CAM



## High-Performance Computing

Memristor-based CAM enables ultra-fast, low-power content-addressable searches in data centers, powering next-gen AI and high-performance computing applications.



## Internet of Things

The compact, energy-efficient design of memristor-based CAM makes it ideal for powering intelligent edge devices and IoT sensors in smart homes, cities, and industrial environments.



## Machine Learning Acceleration

Memristor-based CAM can accelerate key operations in neural networks and machine learning models, enabling more efficient and powerful AI/ML systems.



## Biometric Security

The high-speed lookup capabilities of memristor-based CAM make it well-suited for biometric identification and authentication applications like facial recognition and access control.

# Challenges in Memristor-based CAM Implementation:

## Memristor Variability

Memristors exhibit significant device-to-device and cycle-to-cycle variations due to their nanostructured nature. This variability can lead to challenges in maintaining consistent performance and reliability in large-scale CAM arrays.

## Sneak Path Issue

The high density of memristor-based CAM arrays can lead to current leakage through unselected devices, known as the sneak path issue. This can interfere with the accurate sensing of stored data, requiring complex addressing and sensing schemes.

## Endurance Limitations

Memristors have a limited endurance, meaning they can only withstand a finite number of write/erase cycles before their performance degrades. This can limit the lifetime and reliability of memristor-based CAM systems.

## Power Consumption

The high switching speed and low-power operation of memristors can be advantageous, but the overall power consumption of large-scale CAM arrays may still be a challenge, requiring careful circuit design and optimization.

# Ongoing Research and Developments

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## 1. Memristor Device Scaling

Ongoing research aims to further scale down memristor devices to achieve higher density and energy efficiency for large-scale CAM applications.

2

## 2. Multilevel Memristive States

Exploiting the analog nature of memristors, researchers are investigating multi-level storage to increase the memory capacity of memristor-based CAM.

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## 3. Memristor-based In-Memory Computing

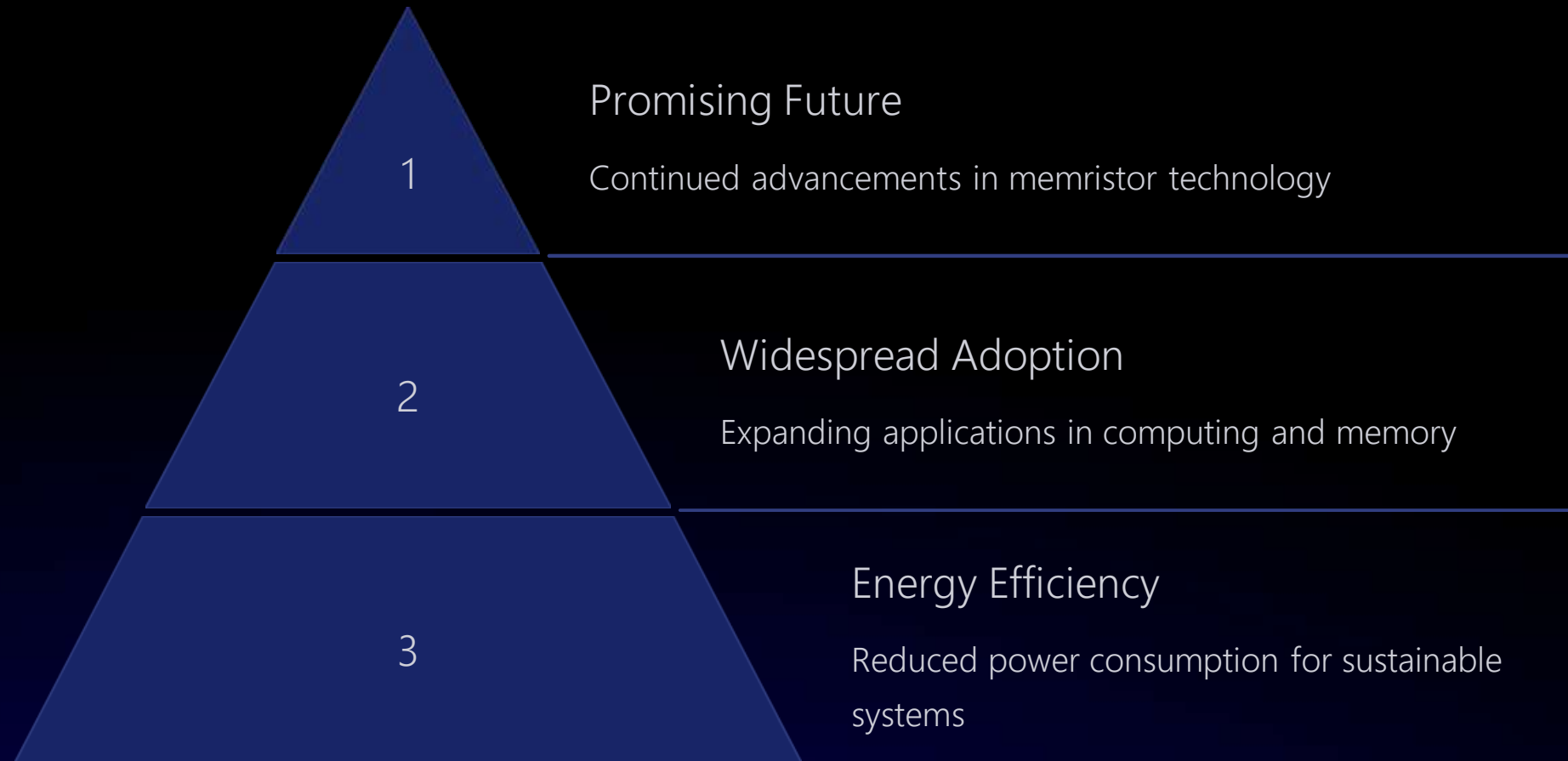
Innovative architectures that tightly integrate memristor-based CAM with processing units are being explored to enable highly efficient in-memory computing.

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## 4. Memristor Reliability Improvements

Ongoing work focuses on enhancing the endurance, retention, and variability of memristor devices to ensure reliable operation of memristor-based CAM systems.

# Conclusion and Future Outlook



In conclusion, memristor-based content addressable memory represents a highly promising technology with the potential to revolutionize various computing and memory applications. As research and development continue, we can expect to see further advancements in memristor device characteristics, leading to widespread adoption of this energy-efficient technology across diverse domains. The future outlook for memristor-based CAM is bright, with exciting possibilities for enhanced computational capabilities and sustainable, low-power systems.

Thank You